



PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**Applicant(s)** J.O. Chu, et al.

**Examiner:** Savitri Mulpuri

**Serial No.:** 09/838,892

**Art Unit:** 1665

**Filed:** April 20, 2003

**Docket:** YOR920010308US1 (16315)

**For:** EPITAXIAL AND POLYCRYSTALLINE  
GROWTH OF  $\text{Si}_{1-x}\text{Ge}_x\text{C}_y$  AND  $\text{Si}_{1-y}\text{C}_y$   
ALLOY LAYERS ON Si By UHV-CVD

**Dated:** March 12, 2003

Commissioner for Patents  
Washington, DC 20231

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AMENDMENT AND RESPONSE

Sir:

In response to the Office Action dated December 12, 2002, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

IN THE CLAIMS:

Please cancel Claims 4, 5, 17 and 18, without prejudice or disclaimer, and please amend

Claims 1, 12, 13, 14, 27 and 28 to read as follows:

1. (Amended) A method for forming an alloy layer of silicon carbon on a

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CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231 on March 12, 2003.

Dated: March 12, 2003

*Janet Grossman*  
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